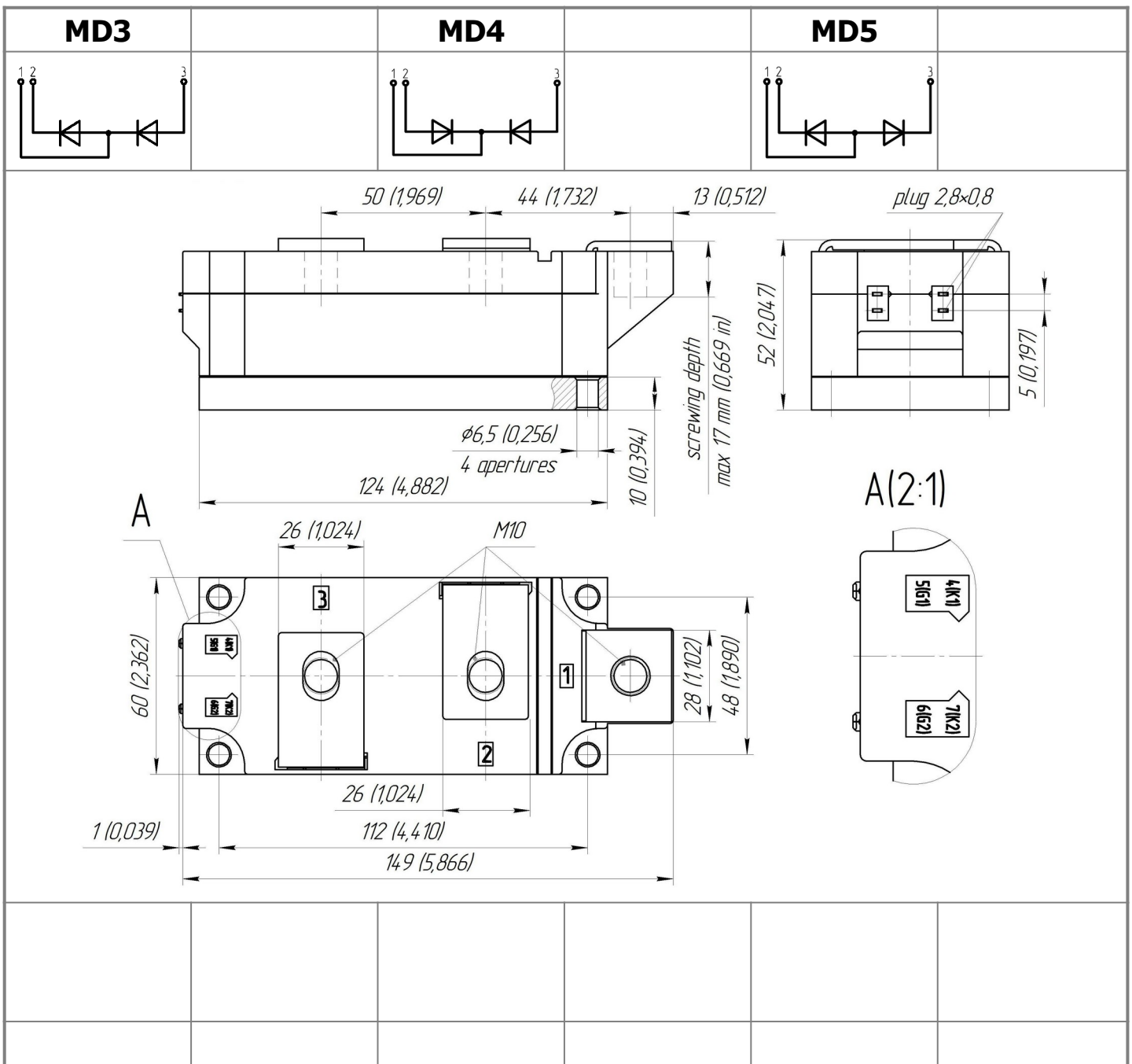




Electrically isolated base plate  
 Industrial standard package  
 Simplified mechanical design, rapid assembly  
 Pressure contact

**Double Diode Module  
 For Phase Control  
 MDx-660-18-A2**

Average forward current				$I_{FAV}$	660 A			
Repetitive peak reverse voltage				$V_{RRM}$	1000 ÷ 1800 V			
$V_{RRM}, V$	1000	1100	1200	1300	1400	1500	1600	1800
Voltage code	10	11	12	13	14	15	16	18
$T_j, °C$	- 40 ÷ 150							



All dimensions in millimeters (inches)


## MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions
<b>ON-STATE</b>				
$I_{FAV}$	Average forward current	A	660	$T_c=100\text{ }^\circ\text{C}$ ; 180° half-sine wave; 50 Hz
$I_{FRMS}$	RMS forward current	A	1036	
$I_{FSM}$	Surge forward current	kA	19.0 22.0	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p=10\text{ ms}$ ; single pulse; $V_R=0\text{ V}$ ;
			20.0 23.0	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p=8.3\text{ ms}$ ; single pulse; $V_R=0\text{ V}$ ;
$I^2t$	Safety factor	$A^2s\cdot 10^3$	1800 2400	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p=10\text{ ms}$ ; single pulse; $V_R=0\text{ V}$ ;
			1600 2100	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p=8.3\text{ ms}$ ; single pulse; $V_R=0\text{ V}$ ;
<b>BLOCKING</b>				
$V_{RRM}$	Repetitive peak reverse voltages	V	1000÷1800	$T_{j\min} < T_j < T_{j\max}$ ; 180° half-sine wave; 50 Hz;
$V_{RSM}$	Non-repetitive peak reverse voltages	V	1100÷1900	$T_{j\min} < T_j < T_{j\max}$ ; 180° half-sine wave; single pulse;
$V_R$	Reverse continuous voltages	V	$0.6\cdot V_{RRM}$	$T_j=T_{j\max}$ ;
<b>THERMAL</b>				
$T_{stg}$	Storage temperature	$^\circ\text{C}$	-40 ÷ 50	
$T_j$	Operating junction temperature	$^\circ\text{C}$	-40 ÷ 150	
$T_{c\text{ op}}$	Operating temperature	$^\circ\text{C}$	-40 ÷ 125	
<b>MECHANICAL</b>				
a	Acceleration under vibration	$m/s^2$	50	

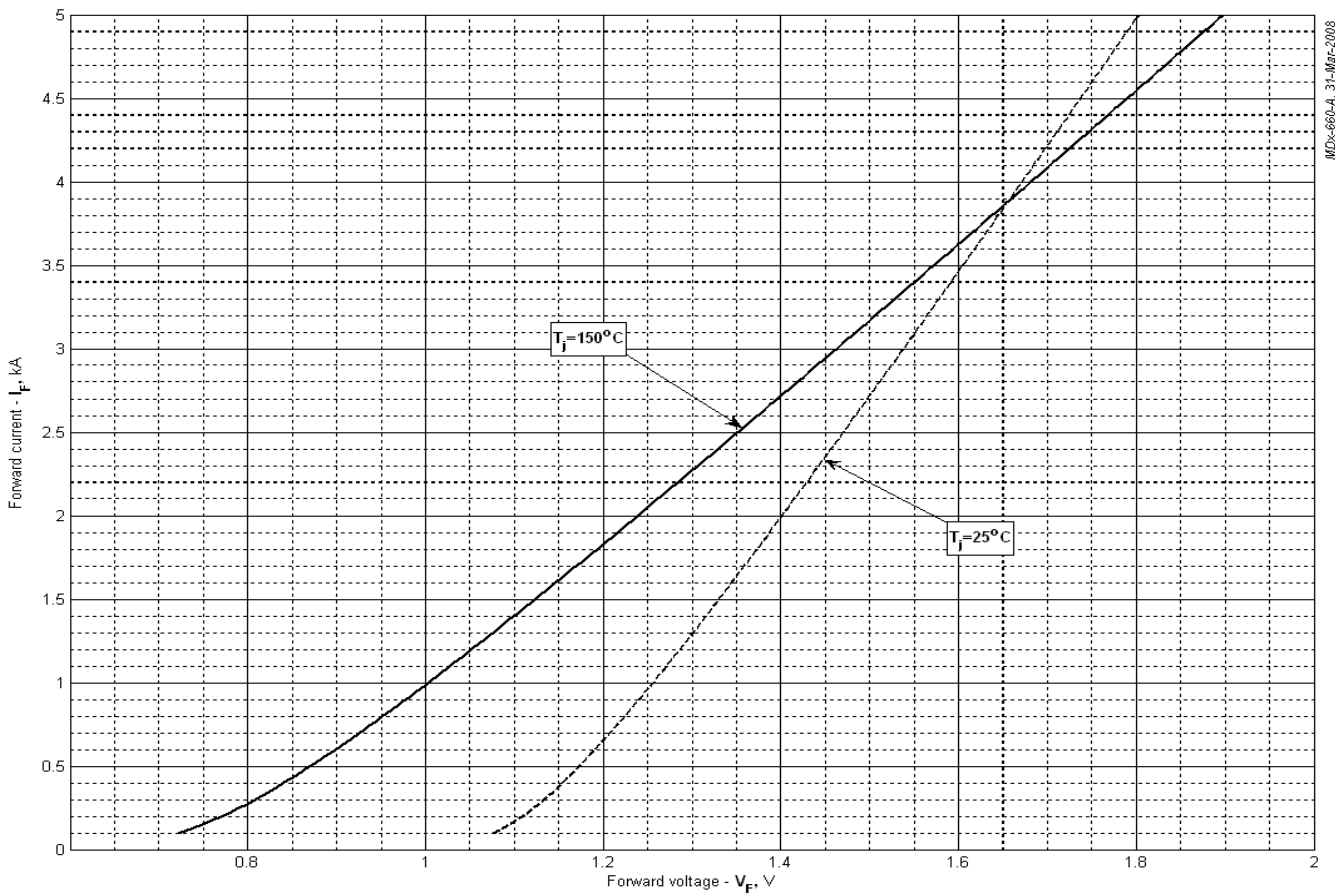
## CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
<b>ON-STATE</b>				
$V_{FM}$	Peak forward voltage, max	V	1.40	$T_j=25\text{ }^\circ\text{C}$ ; $I_{FM}=1978\text{ A}$
$V_{F(TO)}$	Forward threshold voltage, max	V	0.78	$T_j=T_{j\max}$ ;
$r_T$	Forward slope resistance, max	$m\Omega$	0.230	$0.5\pi I_{FAV} < I_T < 1.5\pi I_{FAV}$
<b>BLOCKING</b>				
$I_{RRM}$	Repetitive peak reverse current, max	mA	50	$T_j=T_{j\max}$ ; $V_R=V_{RRM}$
<b>SWITCHING</b>				
$Q_{rr}$	Total recovered charge, max	$\mu\text{C}$	1750	$T_j=T_{j\max}$ ; $I_{TM}=660\text{ A}$ ;
$t_{rr}$	Reverse recovery time, max	$\mu\text{s}$	24	$di_R/dt=-10\text{ A}/\mu\text{s}$ ;
$I_{rrM}$	Peak reverse recovery current, max	A	146	$V_R=100\text{ V}$
<b>THERMAL</b>				
$R_{thjc}$	Thermal resistance, junction to case			180° half-sine wave, 50 Hz
	per module	$^\circ\text{C}/\text{W}$	0.0325	
	per arm	$^\circ\text{C}/\text{W}$	0.0650	
	per module	$^\circ\text{C}/\text{W}$	0.0310	
$R_{thch}$	Thermal resistance, case to heatsink			DC
	per module	$^\circ\text{C}/\text{W}$	0.0100	
	per arm	$^\circ\text{C}/\text{W}$	0.0200	
	per arm	$^\circ\text{C}/\text{W}$	0.0200	
<b>INSULATION</b>				
$V_{ISOL}$	Insulation test voltage	kV	3.00	Sine wave, 50 Hz;
			3.60	RMS
				t=60 sec
				t=1 sec

<b>MECHANICAL</b>				
M <sub>1</sub>	Mounting torque (M6) <sup>1)</sup>	Nm	6.00	Tolerance ± 15%
M <sub>2</sub>	Terminal connection torque (M10) <sup>1)</sup>	Nm	12.00	Tolerance ± 15%
w	Weight, max	g	1500	

<b>PART NUMBERING GUIDE</b>						<b>NOTES</b>					
MD	3	-	660	-	18	-	A2	-	N		<sup>1)</sup> The screws must be lubricated
1	2		3		4		5		6		
1. MD - Rectifier Diode 2. Circuit Schematic: 3 – serial connection 4 – common Cathode 5 – common Anode 3. Average Forward Current, A 4. Voltage Code 5. Package Type (M.A2) 6. Ambient Conditions: N – Normal											
		UL certified file-No. E255404									

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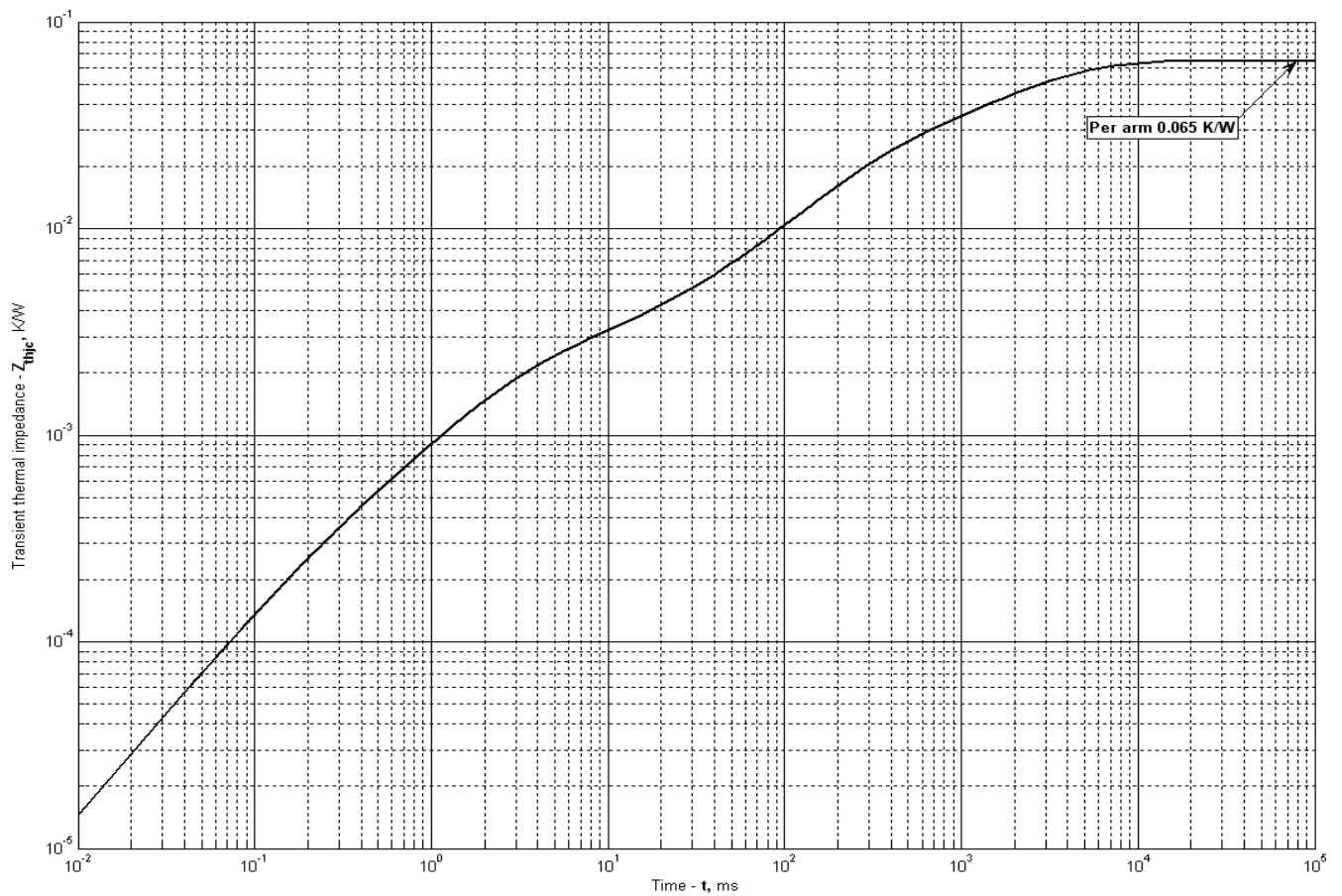
**Fig 1 – On-state characteristics of Limit device**

Analytical function for On-state characteristic:

$$V_F = A + B \cdot i_F + C \cdot \ln(i_F + 1) + D \cdot \sqrt{i_F}$$

	Coefficients for max curves	
	$T_j = 25^\circ\text{C}$	$T_j = T_{j,\text{max}}$
<b>A</b>	0.997101	0.606247
<b>B</b>	0.095326	0.164879
<b>C</b>	-0.153566	-0.217982
<b>D</b>	0.270074	0.383360

**On-state characteristic model (see Fig. 1)**



**Fig 2 – Transient thermal impedance**

Analytical function for Transient thermal impedance junction to case  $Z_{thjc}$  for DC:

$$Z_{thjc} = \sum_{i=1}^n R_i \left( 1 - e^{-\frac{t}{\tau_i}} \right)$$

Where  $i = 1$  to  $n$ ,  $n$  is the number of terms in the series.

$t$  = Duration of heating pulse in seconds.

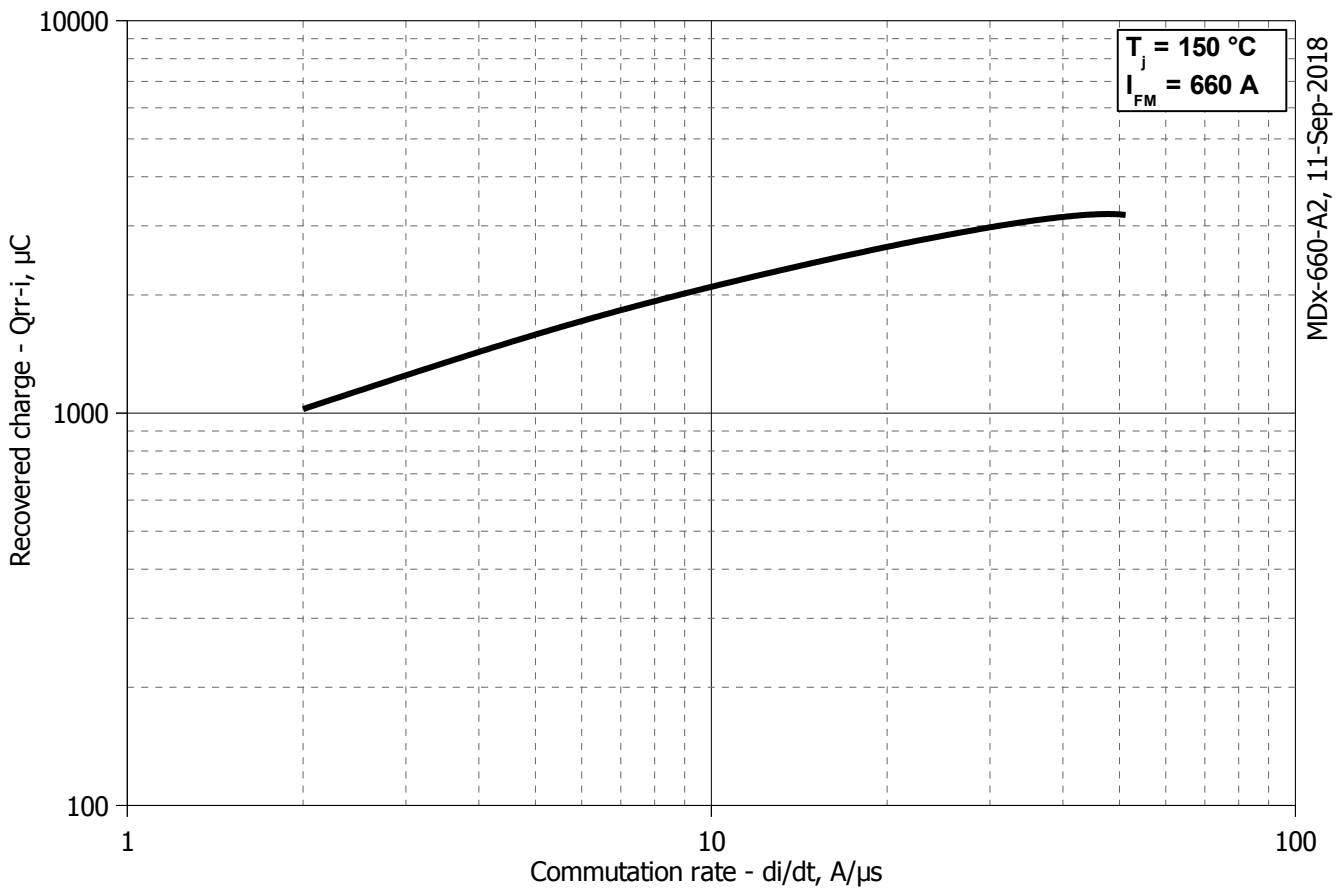
$Z_{thjc}$  = Thermal resistance at time  $t$ .

$R_i$  = Amplitude of  $p_{th}$  term.

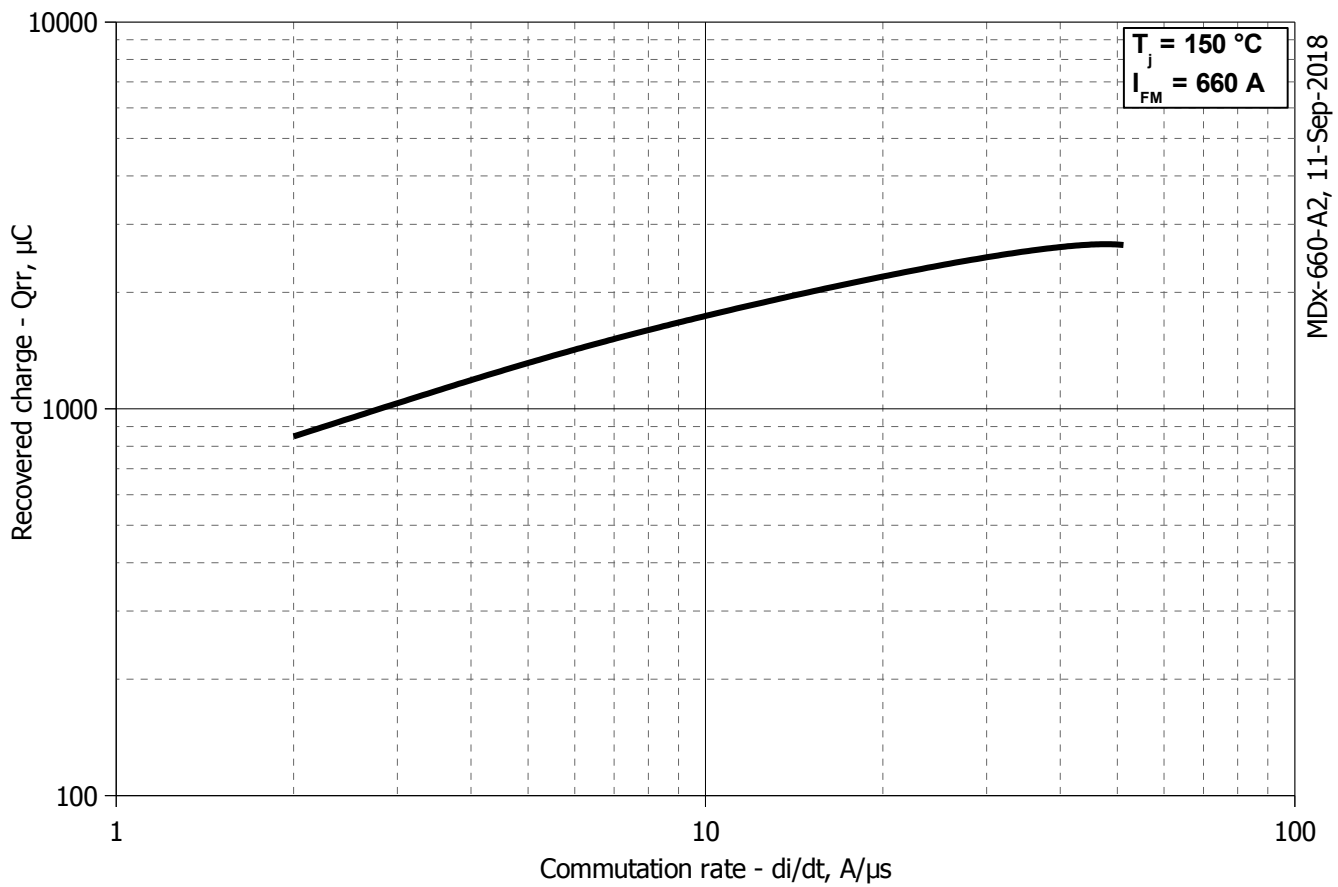
$\tau_i$  = Time constant of  $r_{th}$  term.

$i$	1	2	3	4	5	6
$R_i$ , K/W	0.0344	0.0112	0.01635	0.0006528	0.001791	0.0001363
$\tau_i$ , s	3.132	1.000	0.2335	0.01038	0.002348	0.0002448

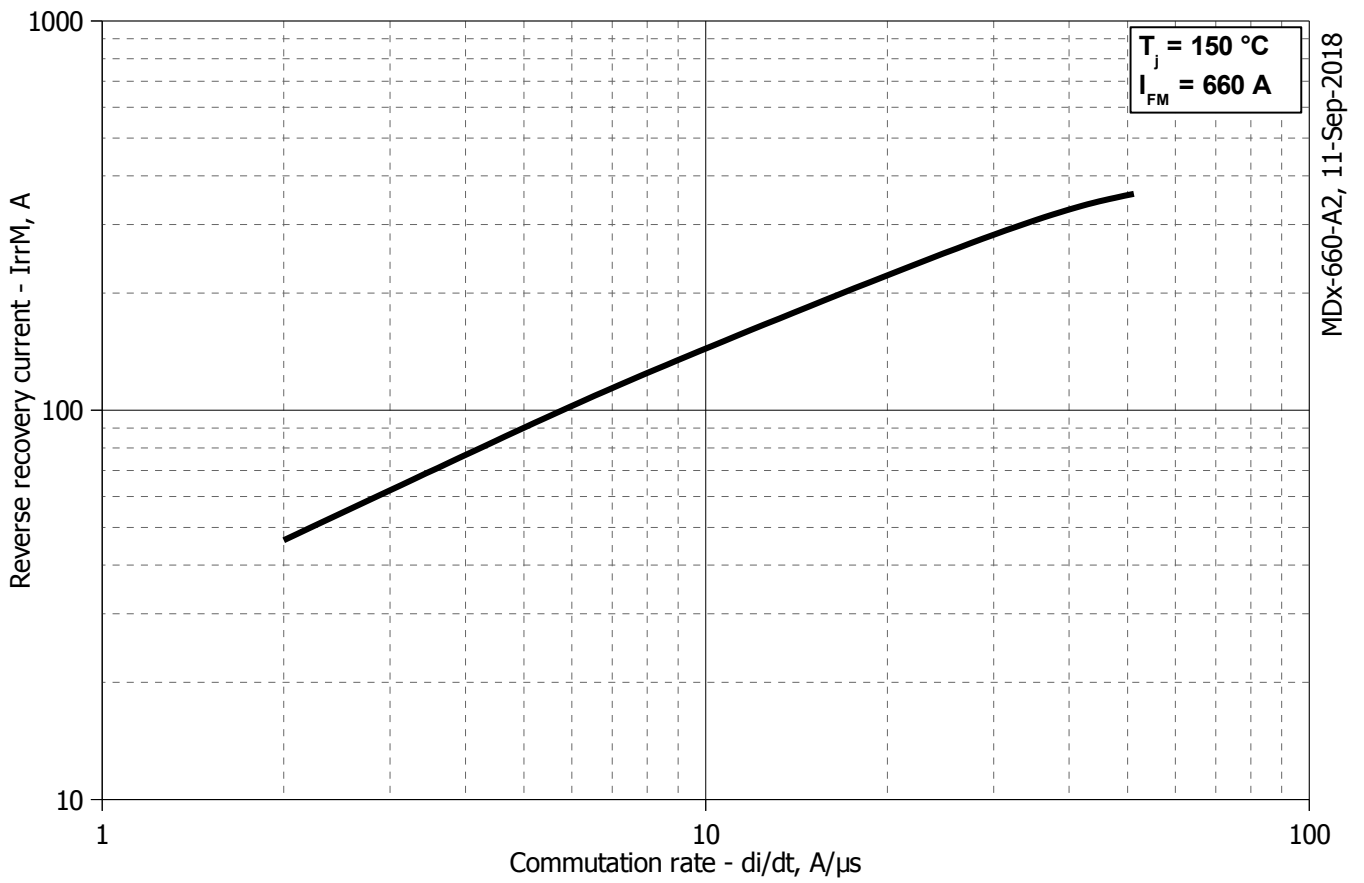
**Transient thermal impedance junction to case  $Z_{thjc}$  model (see Fig. 2)**



**Fig 3 – Total recovered charge,  $Q_{rr-i}$  (integral)**

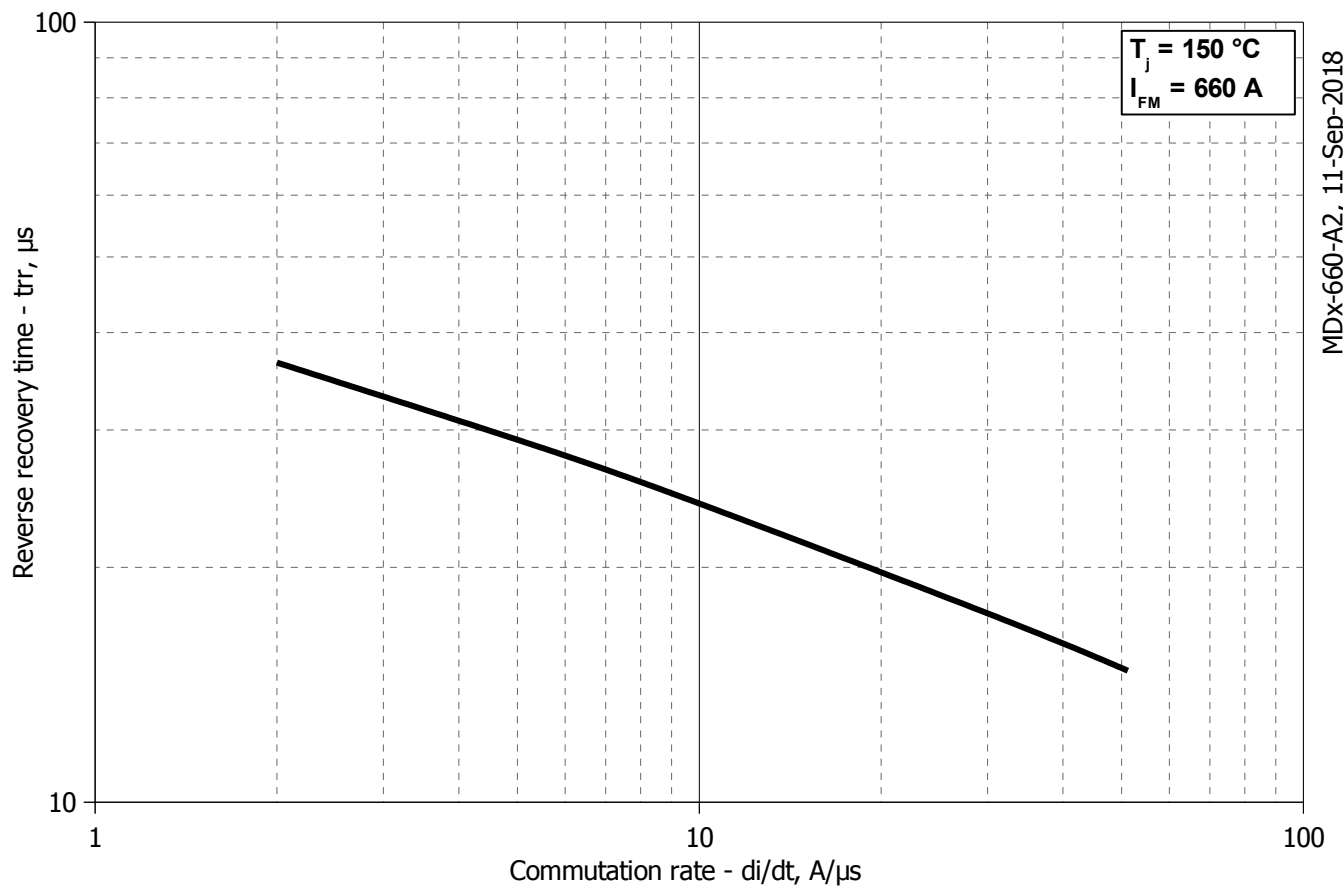


**Fig 4 - Recovered charge,  $Q_{rr}$  (25% chord)**



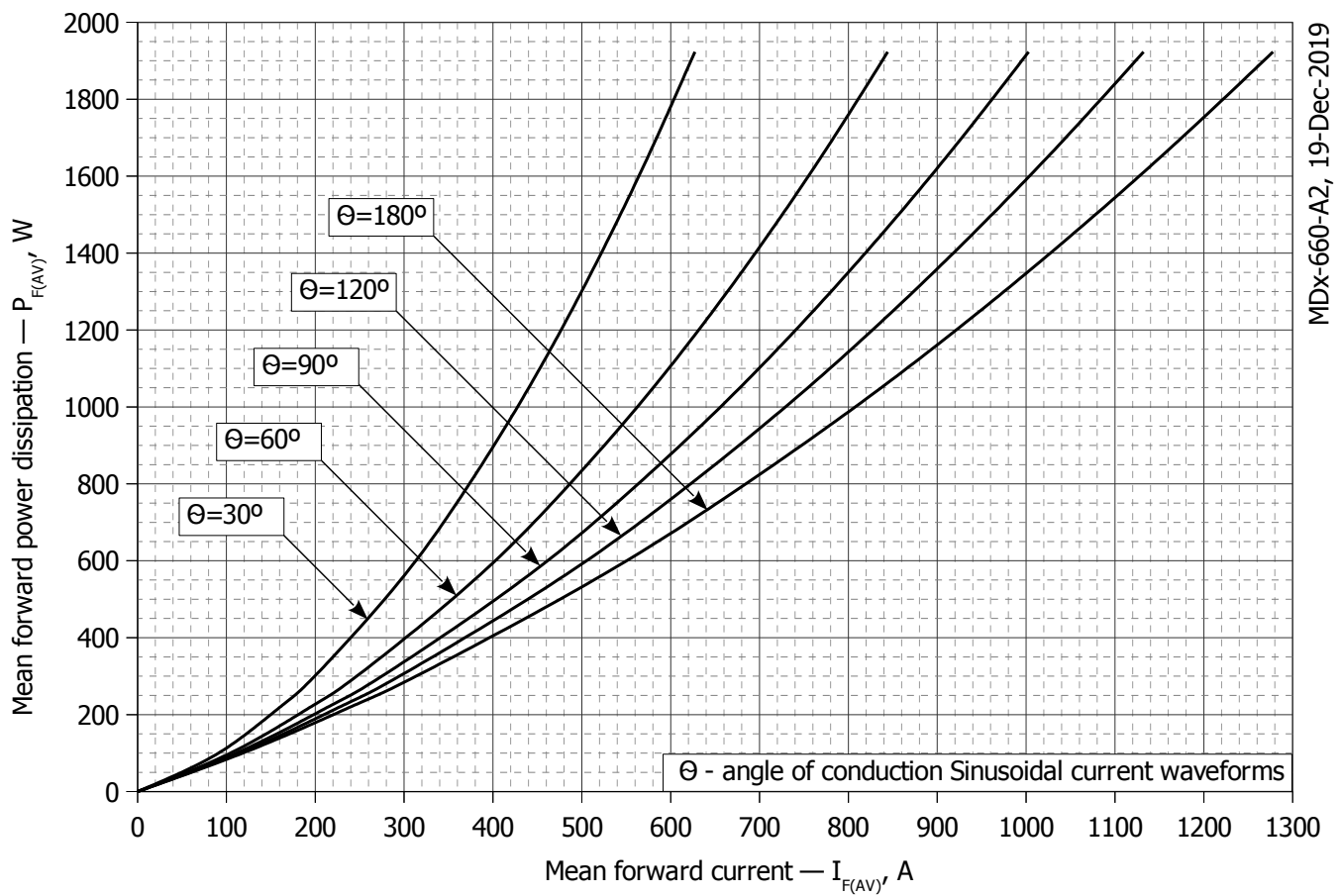
MDx-660-A2, 11-Sep-2018

**Fig 5 – Peak reverse recovery current,  $I_{rm}$**

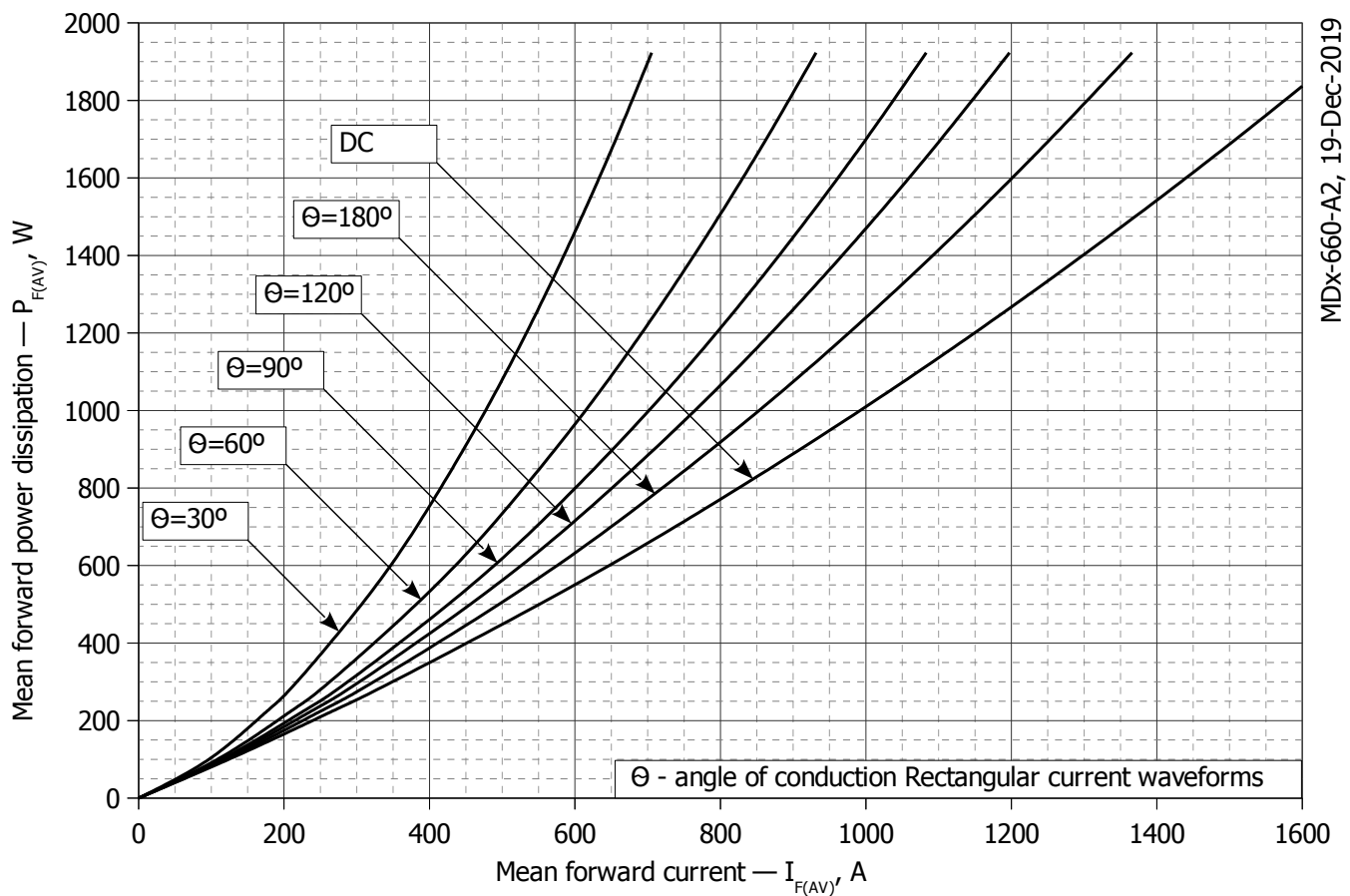


MDx-660-A2, 11-Sep-2018

**Fig 6 – Maximum recovery time,  $t_{rr}$  (25% chord)**

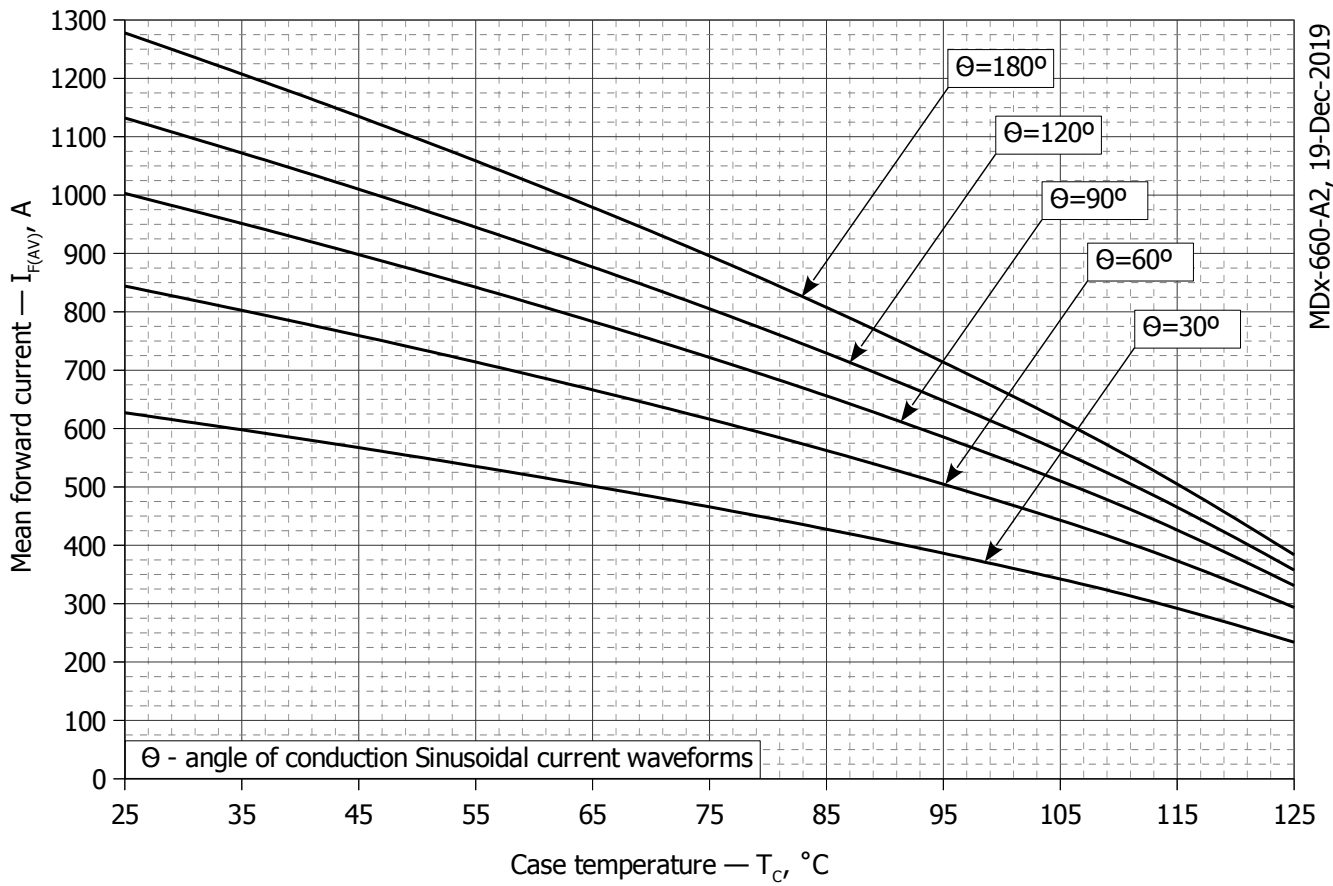


**Fig 7 – On-state power loss (sinusoidal current waveforms)**

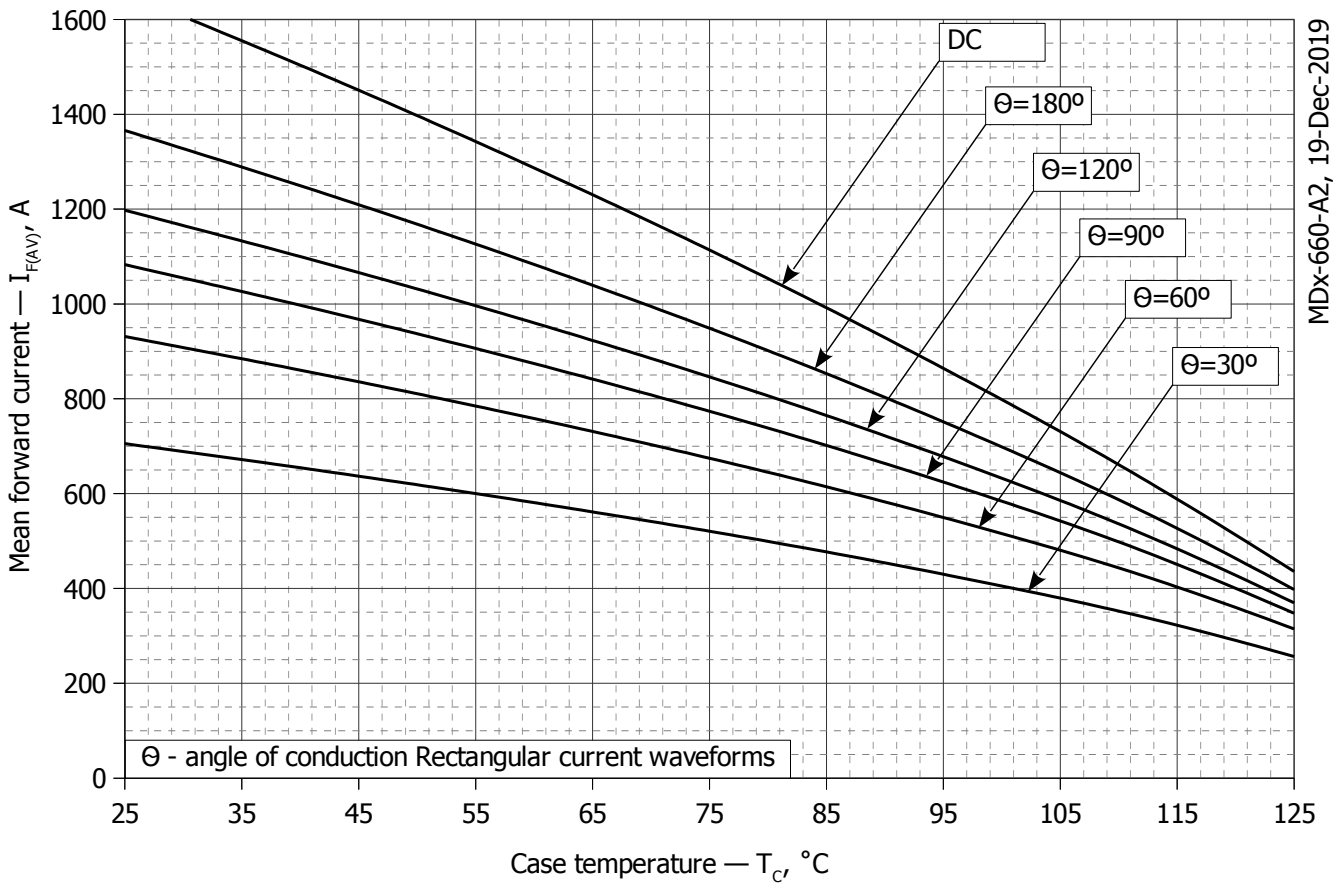


**Fig 8 – On-state power loss (rectangular current waveforms)**

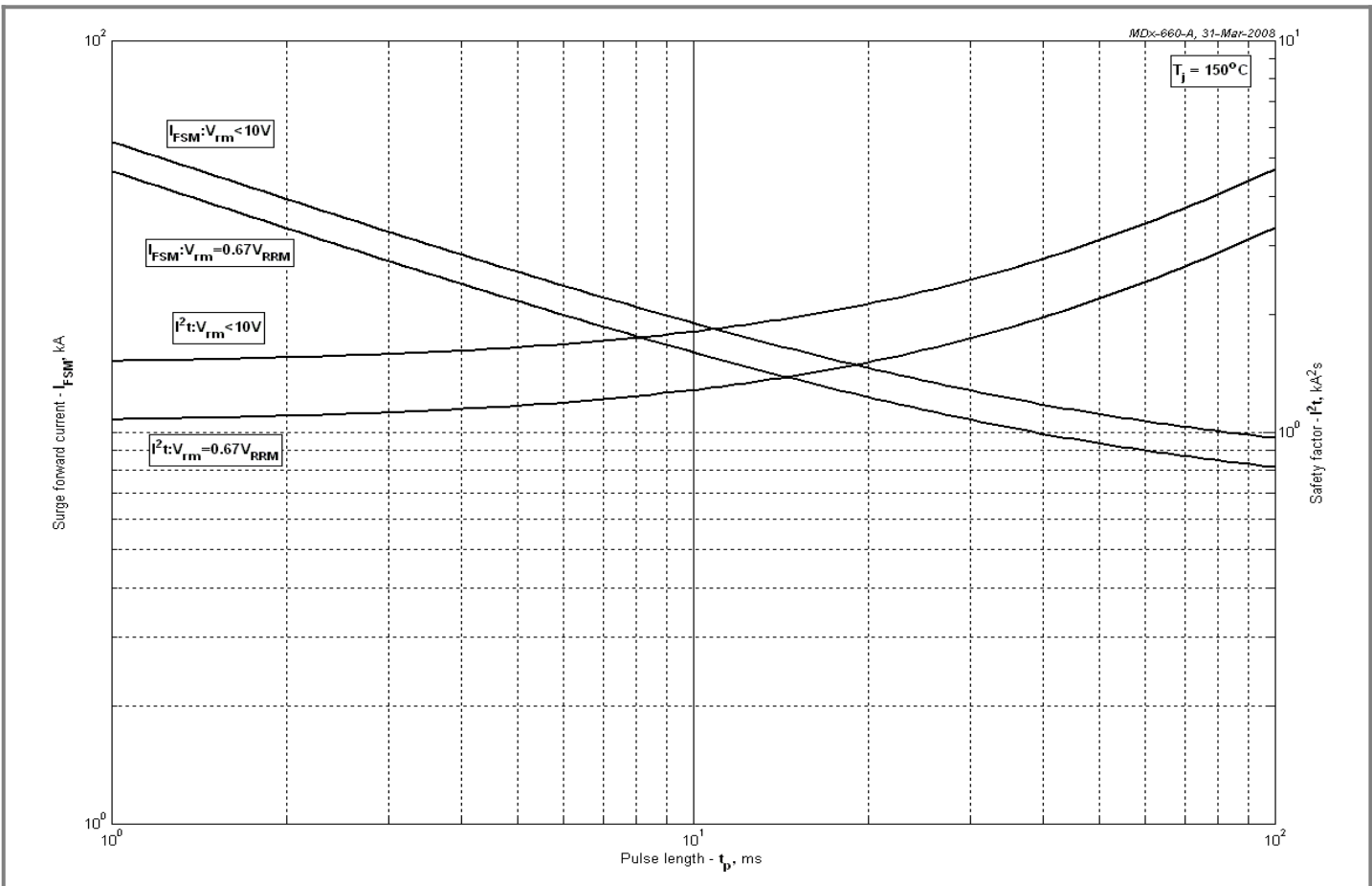




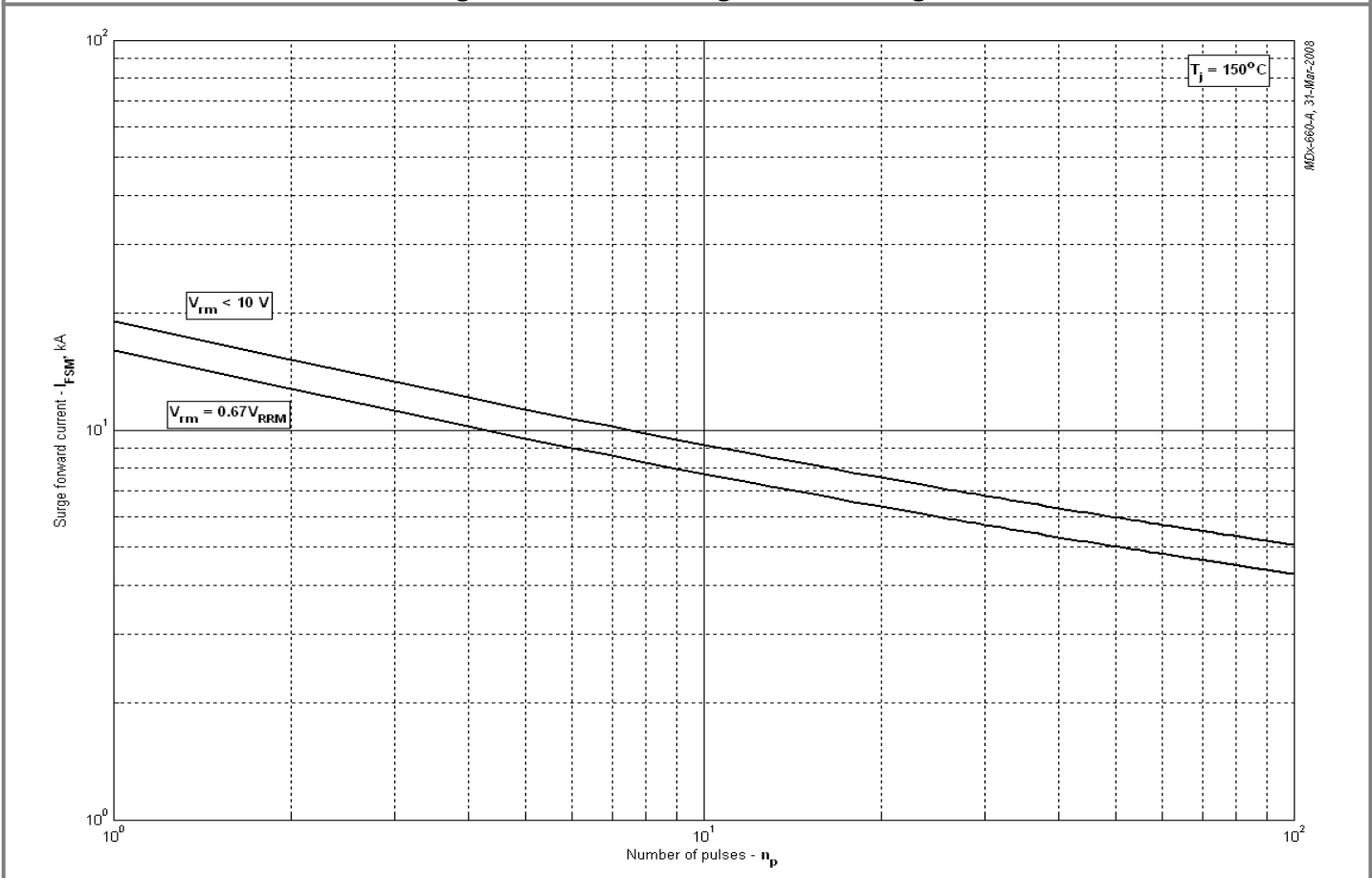
**Fig 9 – Maximum case temperature DSC (sinusoidal current waveforms)**



**Fig 10 – Maximum case temperature DSC (rectangular current waveforms)**



**Fig 11 – Maximum surge and  $I^2t$  ratings**



**Fig 12 – Maximum surge ratings**